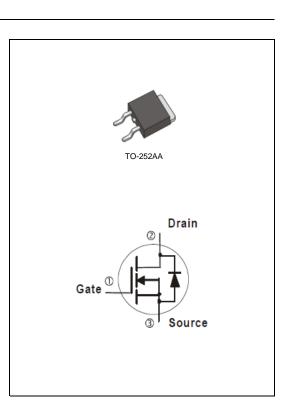
ΡΛΝ	JIT
	SEMI
	CONDUCTOR

# PJD11N06A-AU 60V N-Channel Enhancement Mode MOSFET Voltage 60 V Current 11 A Features • R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V, I<sub>D</sub>@6A<75mΩ</td> • R<sub>DS(ON)</sub>, V<sub>GS</sub>@4.5V, I<sub>D</sub>@3A<90mΩ</td> • High switching speed • Improved dv/dt capability • Low Gate Charge • Low reverse transfer capacitance • AEC-Q101 qualified

- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0104 ounces, 0.297grams



#### **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETE	R	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	60	v	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C		11	A	
	T <sub>c</sub> =100°C	I <sub>D</sub>	7		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	44		
Power Dissipation	T <sub>c</sub> =25°C	Po	30	W	
	T <sub>C</sub> =100°C		15		
Continuous Drain Current (Note 4)	T <sub>A</sub> =25°C	I <sub>D</sub>	3.7	А	
	T <sub>A</sub> =70°C		2.9		
Power Dissipation	T <sub>A</sub> =25°C	PD	2.4	w	
	T <sub>A</sub> =70°C		1.6		
Single Pulse Avalanche Energy	lote 6)	E <sub>AS</sub>	25	mJ	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~175	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ extsf{ heta}JC}$	5	°C/W	
	Junction to Ambient	$R_{ extsf{ heta}JA}$	62.5		

• Limited only By Maximum Junction Temperature



## PJD11N06A-AU

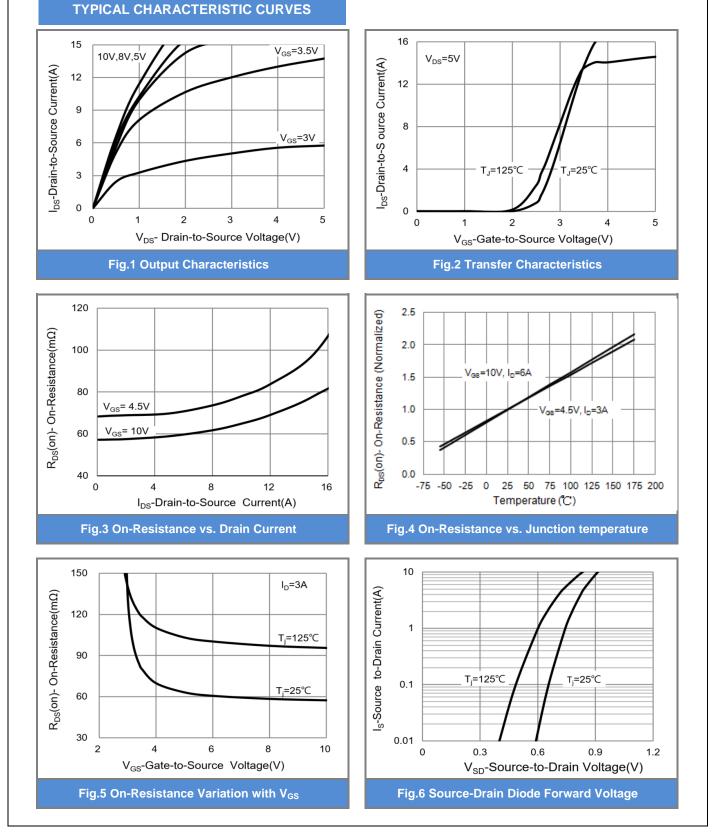
#### **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	-	-	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250$ uA	1	1.8	2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =6A	-	53	75	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =3A	-	61	90	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Qg	$V_{DS}$ =48V, I <sub>D</sub> =6A, $V_{GS}$ =10V <sup>(Note 1,2)</sup>	-	9.3	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	2.2	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	1.9	-	
Input Capacitance	Ciss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1MHZ	-	509	-	pF
Output Capacitance	Coss		-	47	-	
Reverse Transfer Capacitance	Crss		-	23	-	
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =30V, $I_{D}$ =1A, $V_{GS}$ =10V, $R_{G}$ =3.3 $\Omega$ <sup>(Note 1,2)</sup>	-	3.2	-	
Turn-On Rise Time	tr		-	9.7	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	18.5	-	
Turn-Off Fall Time	t <sub>f</sub>	κ <sub>G</sub> =3.3Ω	-	6.4	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					44	A
Diode Forward Current	I <sub>S</sub>		-	-	11	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.75	1	V

NOTES :

- 1. Pulse width
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5.  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

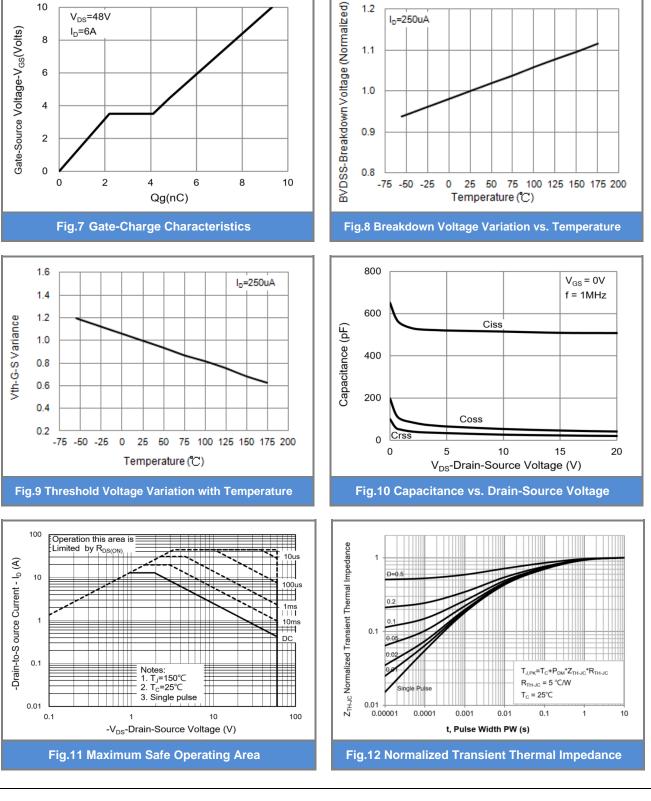
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#### 

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1.2

1.1

Ip=250uA

#### **TYPICAL CHARACTERISTIC CURVES**

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PANJ SFMI CONDUCTOR

10

8

V<sub>DS</sub>=48V

I<sub>D</sub>=6A



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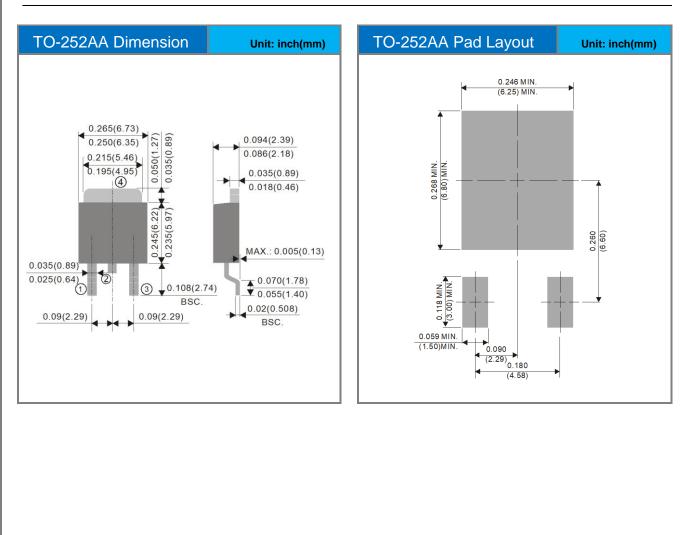


## PJD11N06A-AU

#### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD11N06A-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D11N06A	Halogen free

#### Packaging Information & Mounting Pad Layout





### PJD11N06A-AU

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